

SID4-NIR

WAVE FRONT SENSOR



↓ SPECIFICATIONS

Wavelength range	1.5 – 1.6 μm
Aperture dimension	3.6 x 4.8 mm ²
Spatial resolution	29.6 μm
Phase & intensity sampling	160 x 120
Resolution (Phase)	< 11 nm RMS
Accuracy	15 nm RMS
Acquisition rate	> 60 fps
Real-time processing frequency	> 10 fps (full resolution)
Dimensions (w x h x l)	44 x 33 x 57.5 mm
Weight	~250 g

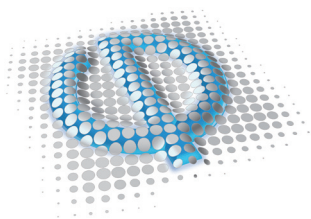
→ The SID4-NIR wavefront sensor covers the near infrared region from **1.5 μm to 1.6 μm** . Its patented technology offers very high resolution which ensures accurate measurement. It also offers compactness and ease of use.

For **laser metrology**, the SID4-NIR gives an exhaustive characterization: aberrations, M^2 , intensity profiles, beam parameters...

For **lens testing**, the SID4-NIR is the perfect tool to characterize NIR objective lenses. It provides both wavefront aberrations and MTF in a single shot.

➤ KEY FEATURES

- Very high resolution (160 x 120)
- High NA measurement with no relay lens
- Compact and insensitive to vibration for easy integration in an optical bench
- Cost-effective solution for near infrared

**PHASICS S.A.**

Bâtiment Explorer
Espace Technologique
Route de l'Orme des Merisiers
91190 Saint-Aubin
FRANCE

Tel : +33(0)1 80 75 06 33

contact@phasics.fr

www.phasics.fr

PHASICS CORP.

600 California Street
11th Floor
San Francisco CA 94108
USA

Tel : +1 415 610 9741